

DIRECTORATE OF GOVERNMENT EXAMINATIONS, CHENNAI- 6
HIGHER SECONDARY SECOND YEAR EXAMINATION - MAY - 2022
PHYSICS KEY ANSWER

NOTE:

1. Answers written with Blue or Black ink only to be evaluated.
2. Choose the most suitable answer in Part A from the given alternatives and write the option code and their corresponding answer.
3. For answers in Part – II , Part – III , Part – IV like reasoning , explanation, narration, description and listing of points, students may write in their own words but without changing the concepts and without skipping any point.
4. In numerical problems if formula is not written , marks should be given for the remaining correct steps.
5. In graphical representation, physical variables for X-axis and Y-axis should be marked.

TOTAL MARKS : 70

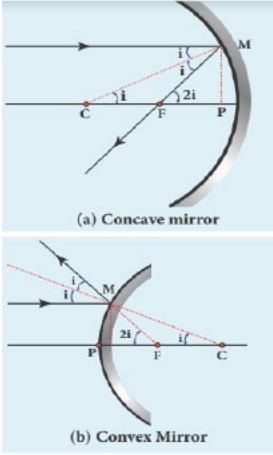
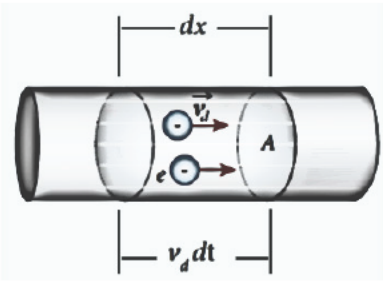
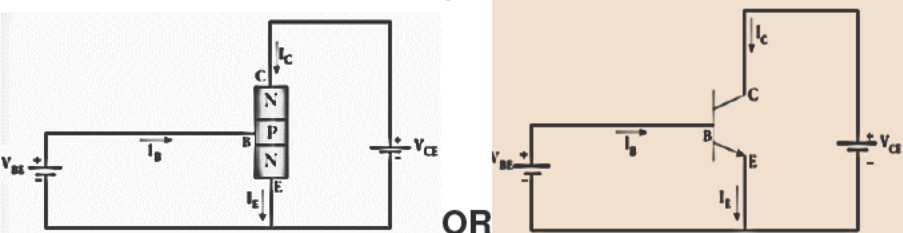
PART - I

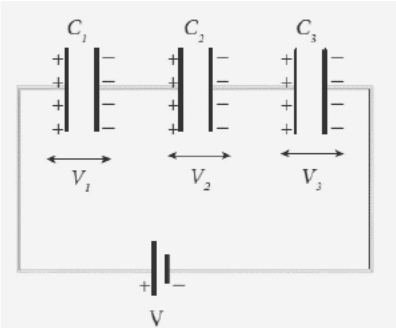
Answer all the questions.

15 X 1 = 15

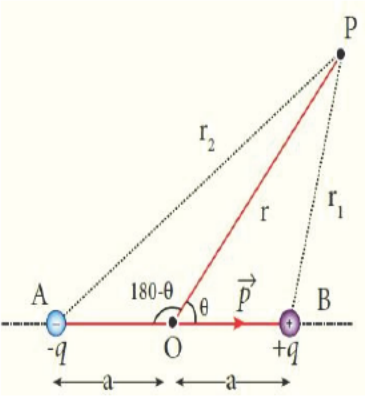
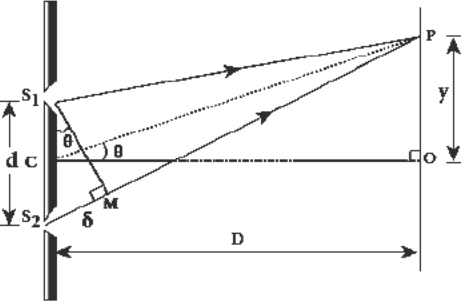
Q.NO	OPTION	TYPE – A	Q.NO	OPTION	TYPE B
1	b	Peacock feather	1	d	Frequency modulation
2	a	decrease by 4 times	2	a	Thermionic
3	d	Frequency modulation	3	a	decrease by 4 times
4	d	All the above	4	b	γ - rays
5	b	3×10^{-2} C	5	a	12 cm
6	b	γ rays	6	b	3×10^{-2} C
7	a	12 cm	7	b	Peacock feather
8	a	$\frac{R}{4}$	8	b	$\sqrt{\frac{2}{3}} \beta I l$
9	b	$\sqrt{\frac{2}{3}} \beta I l$	9	d	All the above
10	a	Thermionic	10	d	0.83
11	d	337.5 C	11	d	$r_n \propto n$
12	d	Negative	12	c	Polarisation
13	d	0.83	13	d	Negative
14	d	$r_n \propto n$	14	a	$\frac{R}{4}$
15	c	Polarisation	15	d	337.5 C

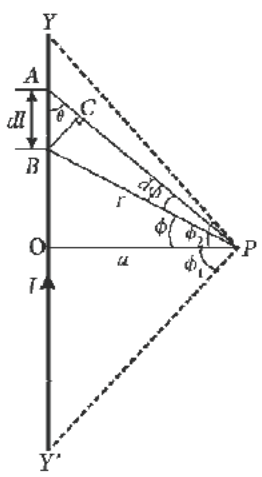
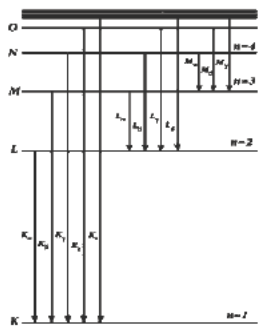
16	<p>Corona Discharge : The total charge of the charged conductor near the sharp edge reduces</p> <p>(or)</p> <p>Leakage of charges from the sharp points of the charged conductor</p>		2
17	<p>The current sensitivity of a galvanometer can be increased by</p> <ol style="list-style-type: none"> 1. increasing the number of turns (N) 2. increasing the magnetic induction (B) 3. increasing the area of the coil (A) 4 by decreasing the couple per unit twist of the suspension wire (K) <p>(or)</p> <p>$I_s = \frac{\theta}{I} = \frac{NAB}{K}$ Only formula</p>	<p>1/2</p> <p>1/2</p> <p>1/2</p> <p>1/2</p> <p>1</p>	2
18	<p>Work function : The minimum energy needed for an electron to escape from the metal surface</p> <p>Unit : electron volt (eV) (or) J</p> <p>(or)</p> <p>$h\nu_0 = \phi_0$, ν_0 – threshold frequency</p>	<p>1 1/2</p> <p>1/2</p> <p>1</p>	2
19	<p>R = R₀ A^{1/3}</p> <p>$R = 1.2 \times 10^{-15} \times (197)^{1/3}$</p> <p>$R = 6.97 \times 10^{-15} \text{ m}$ or R = 6.97 F</p>	<p>1</p> <p>1/2</p> <p>1/2</p>	2
20	Fleming's right hand rule: Correct Statement		2
21	Doping: The process of adding impurities to the intrinsic semiconductor		2
22	<p>Displacement current: The current which comes into play in the region in which the electric field or the electric flux is changing with time.</p> <p>(or)</p> <p>$i_d = \epsilon_0 \frac{d\phi_E}{dt}$ Only formula</p>	<p>2</p> <p>1</p>	2
23	<p>Electrical resistivity : The resistance offered to current flow by a conductor of unit length having unit area of cross section.</p> <p>(or)</p> <p>$\rho = \frac{RA}{l}$ (or) $\rho = \frac{R(\pi r^2)}{l}$ (or) $\rho = R$ if $l = 1\text{m}, A = 1\text{m}^2$</p>	<p>2</p> <p>1</p>	2
24	<p>$n = \frac{\sin(\frac{A+D}{2})}{\sin(\frac{A}{2})}$</p> <p>substitution</p> <p>$n=1.532$</p>	<p>1</p> <p>1/2</p> <p>1/2</p>	2

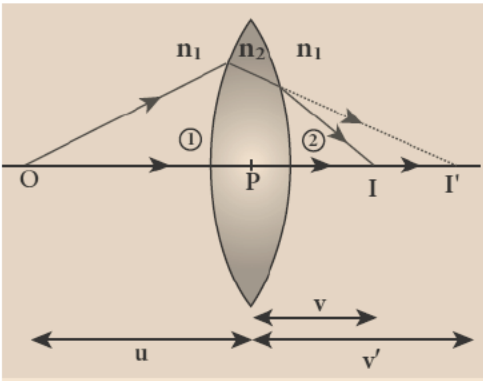
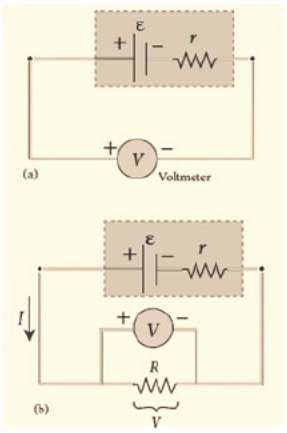
<p>25</p>	<p>Any one Diagram</p> $\left. \begin{aligned} \tan i &= \frac{PM}{PC}, \tan 2i = \frac{PM}{PF} \\ \tan i &\approx i, \tan 2i \approx 2i \\ i &= \frac{PM}{PC}, 2i = \frac{PM}{PF} \\ 2PF &= PC \\ 2f &= R \text{ or } f = \frac{R}{2} \end{aligned} \right\}$	 <p>(a) Concave mirror</p> <p>(b) Convex Mirror</p>	<p>1</p> <p>1</p> <p>1</p>	<p>3</p>
<p>26</p>	<p>Diagram (or) Explanation</p> $\left. \begin{aligned} v_d &= \frac{dx}{dt} \\ dQ &= e(Av_d dt)n \\ I &= \frac{dQ}{dt} \\ I &= neAv_d \end{aligned} \right\}$		<p>1</p> <p>1</p> <p>1</p>	<p>3</p>
<p>27</p>	<p>Laws of photoelectric effect:</p> <ol style="list-style-type: none"> For a given metallic surface, photoelectrons are emitted only if the frequency of incident light is greater than the minimum threshold frequency. If $(\nu > \nu_0)$ number of photoelectrons emitted is proportional to the intensity of incident radiation. Maximum kinetic energy of photoelectron is independent of the intensity of the incident radiation. Maximum number of photoelectrons is proportional to frequency of incident radiation. There is no time lag between incidence of light and ejection of photoelectrons. 	<p>1</p> <p>1/2</p> <p>1/2</p> <p>1/2</p> <p>1/2</p>	<p>3</p>	
<p>28</p>	<p>Energy configuration.</p>  <p>OR</p>	<p>1</p> <p>1</p> <p>1</p>	<p>3</p>	

29	Any three uses of Polaroid's.	3×1	3	
30	Diagram & Explanation $V = V_1 + V_2 + V_3$ Upto $\frac{Q}{C_s} = Q \left(\frac{1}{C_1} + \frac{1}{C_2} + \frac{1}{C_3} \right)$ $\frac{1}{C_s} = \frac{1}{C_1} + \frac{1}{C_2} + \frac{1}{C_3}$ (or) uivalent Statement		1 1/2 1/2 1	3
31	(i) Formula $l = \frac{nh}{2\pi}$ Substitution $l = 5.25 \times 10^{-34} \text{ kg m}^2\text{s}^{-1}$ (ii) Formula $v = \frac{l}{mr}$ Substitution $v = 4.4 \times 10^5 \text{ ms}^{-1}$ (or) e itive method (ii) $v = \frac{1}{137} \frac{c}{n}$ $v = \frac{1}{137} \frac{3 \times 10^8}{5}$ $v = 4.4 \times 10^5 \text{ ms}^{-1}$	1/2 1/2 1/2 1/2 1/2 1/2 1/2	3	
32	Any three r of Lorentz force OR $F_m = qvB \sin \theta$ (OR) $\vec{F}_m = q(\vec{v} \times \vec{B})$	3×1 1	3	
33	(i) Impedance $Z = \sqrt{R^2 + (X_L - X_C)^2}$ Substitution $Z = \sqrt{30^2 + (84 - 144)^2}$ $Z = 50 \Omega$ (ii) Phase Angle $\tan \phi = \frac{X_L - X_C}{R}$ Substitution $\tan \phi = \frac{184 - 144}{30} = 1.33$ Voltage leads current by $\phi : \tan^{-1} \left(\frac{4}{3} \right) = \tan^{-1}(1.33) = 53.1^\circ$	1/2 1/2 1/2 1/2 1/2 1/2	3	

<p>34 (a)</p>	<p>Full wave rectifier : Circuit Diagram</p> <p>Construction</p> <p>Positive half cycle</p> <p>Negative half cycle</p> <p>Efficiency 81.2 %</p> <p>no errors</p>		<p>1</p> <p>1/2</p> <p>1</p> <p>1</p> <p>1/2</p> <p>1</p>	<p>5</p>
<p>34 (b)</p>	<p>Transformer : Principle : Mutual induction</p> <p>Diagram & Explanation</p> $\left. \begin{aligned} \varepsilon_P &= -N_P \frac{d\phi_B}{dt} \text{ (or) } v_P = -N_P \frac{d\phi_B}{dt} \\ \varepsilon_S &= -N_S \frac{d\phi_B}{dt} \text{ (or) } v_S = -N_S \frac{d\phi_B}{dt} \end{aligned} \right\}$ <p>For an ideal transformer, input power = output power</p> $v_P i_P = v_S i_S$ $\frac{v_S}{v_P} = \frac{N_S}{N_P} = \frac{I_P}{I_S} = K$ <p>For step up transformer $K > 1$</p> <p>For step down transformer $K < 1$</p>		<p>1/2</p> <p>1</p> <p>1</p> <p>1/2</p> <p>1</p> <p>1</p>	<p>5</p>

35 a	<p>I t c a point due to an electric dipole:</p> <p>Diagram & Explanation</p> $\text{upto } V = \frac{q}{4\pi\epsilon_0} \left(\frac{1}{r_1} - \frac{1}{r_2} \right)$ $\text{Upto } \frac{1}{r_1} = \frac{1}{r} \left(1 + \frac{a \cos \theta}{r} \right)$ $\frac{1}{r_2} = \frac{1}{r} \left(1 - \frac{a \cos \theta}{r} \right)$ $\text{upto } V = \frac{1}{4\pi\epsilon_0} \frac{2aq \cos \theta}{r^2}$ $p = 2aq$ $V = \frac{1}{4\pi\epsilon_0} \frac{p \cos \theta}{r^2} \quad (\text{or}) \quad V = \frac{\vec{p} \cdot \hat{r}}{4\pi\epsilon_0 r^2}$ 	1 1 1/2 1/2 1/2 1	5
35 (b)	<p>o u x periment:</p> <p>Diagram & Explanation</p>  <p>up to $\delta = \frac{dy}{D}$</p> <p>for maxima $\delta = n\lambda$ $n = 0, 1, 2, 3, \dots$</p> $y = n \frac{\lambda D}{d} \quad (\text{or}) \quad y_n = n \frac{\lambda D}{d}$ <p>for minima $\delta = (2n - 1) \frac{\lambda}{2}$ $n = 1, 2, 3, \dots$</p> $y = \frac{(2n - 1) \lambda D}{2d} \quad (\text{or}) \quad y_n = \frac{(2n - 1) \lambda D}{2d}$ <p>Definition of bandwidth</p> <p>Equation for bandwidth light fringe or dark fringe</p> $\beta = \frac{\lambda D}{d}$	1 1 1/2 1/2 1	5

<p>36 (a)</p>	<p style="text-align: center;">ig straight conductor g nt :</p> <p>Diagram & Explanation</p> $d\vec{B} = \frac{\mu_0 I dl \sin \theta}{4\pi r^2} \hat{n}$ <p>upto $d\vec{B} = \frac{\mu_0 I d\phi}{4\pi r} \hat{n}$</p> $d\vec{B} = \frac{\mu_0 I}{4\pi a} ; \phi d\phi \hat{n}$ <p>upto $\vec{B} = \frac{\mu_0 I}{4\pi a} (\sin \phi_1 + \sin \phi_2) \hat{n}$</p> $\phi_1 = \phi_2 = 90' \text{ or } \frac{\pi}{2}$ $\vec{B} = \frac{\mu_0 I}{2\pi a} \hat{n}$ 	<p>1 1/2 1 1/2 1/2 1</p>	<p>5</p>
<p>36 b</p>	<p>Spectral gen atom: with explanations and formula (or) Names of sp t alone</p>	<p>5x1 2</p>	<p>5</p>
<p>37 a(i) 37 a(ii)</p>	<p>Characteristic x-stra: x – narrow peaks at some well – defined wavelengths when the target is bombarded with high energy electrons. This spectrum is called characteristic x – ray spectrum.</p> <p>Explanation with Diagram</p> $\lambda_o = \frac{12400}{V} \text{A}^\circ$ $\lambda_o = 0.62 \text{A}^\circ$ $\nu_o = \frac{c}{\lambda_o}$ $\nu_o = 4.84 \times 10^{18} \text{Hz}$ 	<p>1 2 1 1</p>	<p>5</p>
<p>37 (b)</p>	<p>Spectrum : The definite pattern of colored bands or lines is called as spectrum. Emission Spectrum : The spectrum produced by the emission of light from a substance is called as emission spectrum. (ii) Line Emission Spectra Name and examples (or) Types of Emission spectrum alone</p>	<p>1/2 1 1/2 1 1/2 1 1/2</p>	<p>5</p>

<p>38 a</p>	<p>Len's makers formula:</p> <p>Diagram & Explanation</p>  $\frac{n_2}{v} - \frac{n_1}{u} = \frac{(n_2 - n_1)}{R}$ $\frac{n_2}{v'} - \frac{n_1}{u} = \frac{(n_2 - n_1)}{R_1}$ $\frac{n_1}{v} - \frac{n_2}{v'} = \frac{(n_1 - n_2)}{R_2}$ $\left. \frac{1}{v} - \frac{1}{u} = \left(\frac{n_2}{n_1} - 1\right) \left(\frac{1}{R_1} - \frac{1}{R_2}\right) \right\}$ <p>ie image is formed at the focus of the lens. $u = \infty$, $v = f$</p> $\frac{1}{f} = \left(\frac{n_2}{n_1} - 1\right) \left(\frac{1}{R_1} - \frac{1}{R_2}\right)$ <p>If the lens is kept in air, $n_1 = 1$ and $n_2 = n$.</p> $\frac{1}{f} = (n - 1) \left(\frac{1}{R_1} - \frac{1}{R_2}\right)$	<p>1</p> <p>1/2</p> <p>1/2</p> <p>1/2</p> <p>1 1/2</p> <p>1</p>	<p>5</p>
<p>38 (b)</p>	<p>Cell using voltmeter:</p> <p>Both the diagrams</p> <p>Explanation</p> <p>$V = IR$</p> <p>$V = \varepsilon - Ir$ (or) $Ir = \varepsilon - V$</p> $\frac{Ir}{IR} = \frac{\varepsilon - V}{V}$ <p>Internal resistance $r = \frac{\varepsilon - V}{V} R$</p> 	<p>1</p> <p>1/2</p> <p>1</p> <p>1</p> <p>1/2</p> <p>1</p>	<p>5</p>